

SEARCHED

Class	Sub.	Date	Exmr.
738	199 238 154	6/9/01	→
257	50 69 204 347		
	351 776 773 411 390		

INTERFERENCE SEARCHED

Class	Sub.	Date	Exmr.
257	69	6/11/01	→

SEARCH NOTES (INCLUDING SEARCH STRATEGY)

TEST 1, 2

APPLICANT FORMS
A CMOS DEVICE
WHEREIN THE
NTFT HAS SIDEWALLS
AND THE DTFT
DOES NOT HAVE
SIDEWALLS AND THERE
IS A CRYSTALLIZATION
ELEMENT IN THE
ACTIVE REGION

KEYWORDS

SIDEWALL
SACRIFICIAL SIDEWALL
CMOS & DTFT
CMOS & WIRING
CMOS & METALLIZATION
CMOS & DTFT & NO-SPACE